### DATA SHEET



Solid State Relay OCMOS FET

# PS7122A-1C,PS7122AL-1C

# 8-PIN DIP, 250 V BREAK DOWN VOLTAGE, TRANSFER TYPE 2-ch Optical Coupled MOS FET

### **DESCRIPTION**

The PS7122A-1C and PS7122AL-1C are transfer type solid state relays containing normally open (N.O.) contact and normally close (N.C.) contact on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7122AL-1C has a surface mount type lead.

#### **FEATURES**

- 2 channel type (1 a + 1 b output)
- ★ Low LED operating current (IF = 2 mA)
  - · Designed for AC/DC switching line changer
  - Small package (8-pin DIP)
  - · Low offset voltage
  - PS7122AL-1C: Surface mount type

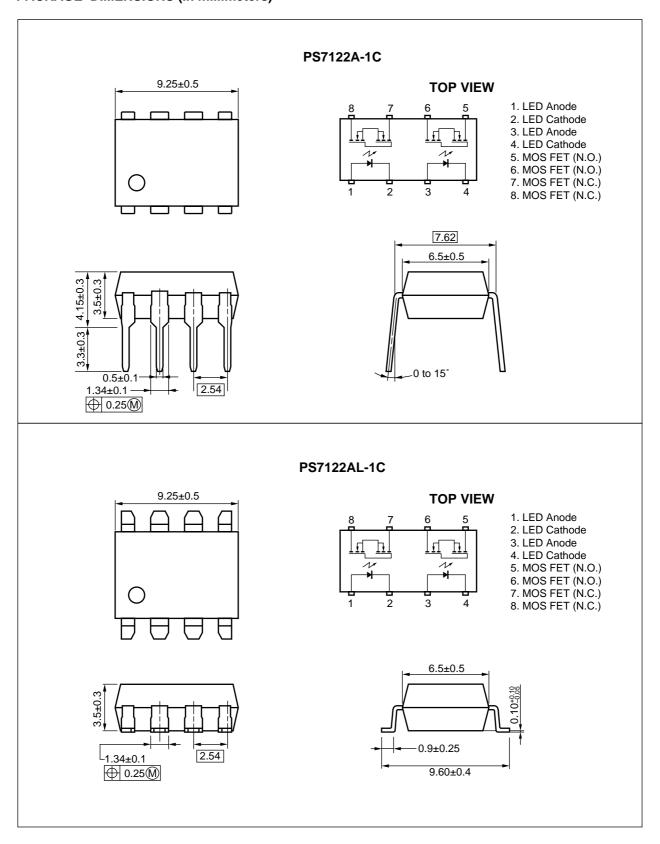
### **APPLICATIONS**

- · Exchange equipment
- · Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

### **PACKAGE DIMENSIONS (in millimeters)**



### **★ ORDERING INFORMATION**

Part Number	Package	Packing Style	Application Part Number <sup>⁴¹</sup>
PS7122A-1C	8-pin DIP	Magazine case 50 pcs	PS7122A-1C
PS7122AL-1C			PS7122AL-1C
PS7122AL-1C-E3		Embossed Tape 1 000 pcs/reel	
PS7122AL-1C-E4			

<sup>\*1</sup> For the application of the Safety Standard, following part number should be used.

# ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	50	mA
	Reverse Voltage	VR	5.0	V
	Power Dissipation	Po	50	mW/ch
	Peak Forward Current*1	IFP	1	Α
MOS FET	MOS FET Break Down Voltage		250	V
	Continuous Load Current	lι	200	mA
	Pulse Load Current <sup>2</sup> (AC/DC Connection)	Ігр	400	mA
	Power Dissipation	Po	375	mW/ch
Isolation Voltage*3		BV	1 500	Vr.m.s.
Total Power Dissipation		Рт	850	mW
Operating Ambient Temperature		TA	-40 to +80	°C
Storage Temperature		T <sub>stg</sub>	-40 to +100	°C

<sup>\*1</sup> PW = 100  $\mu$ s, Duty Cycle = 1 %

## RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	
LED Operating Current	lF	2	10	20	mA	
LED Off Voltage	VF	0		0.5	V	

\*

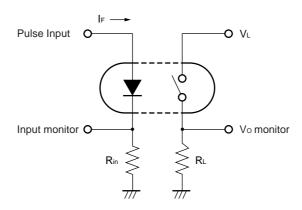
<sup>\*2</sup> PW = 100 ms, 1 shot

<sup>\*3</sup> AC voltage for 1 minute at  $T_A = 25$  °C, RH = 60 % between input and output

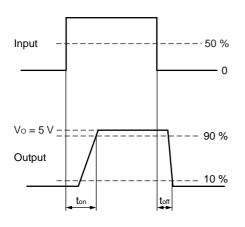
# **★** ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V <sub>R</sub> = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	N.O.: I <sub>F</sub> = 0 mA, V <sub>D</sub> = 250 V		0.03	1.0	μΑ
			N.C.: I <sub>F</sub> = 10 mA, V <sub>D</sub> = 250 V				
	Output Capacitance	Cout	N.O.: V <sub>D</sub> = 0 V, f = 1 MHz		120		pF/ch
			N.C.: I <sub>F</sub> = 10 mA, V <sub>D</sub> = 0 V, f = 1 MHz		340		
Coupled	LED On-state Current	IFon	N.O.: I <sub>L</sub> = 200 mA			2.0	mA
	LED Off-state Current	Foff	N.C.: I <sub>L</sub> = 200 mA			2.0	mA
	On-state Resistance	Ron1	N.O.: I <sub>F</sub> = 10 mA, I <sub>L</sub> = 10 mA		4.5	8.0	Ω
			N.C.: I <sub>F</sub> = 0 mA, I <sub>L</sub> = 10 mA				
		Ron2	N.O.: $I_F = 10 \text{ mA}, I_L = 200 \text{ mA}, t \le 10 \text{ ms}$				
			N.C.: $I_F = 0$ mA, $I_L = 200$ mA, $t \le 10$ ms				
	Turn-on Time <sup>™</sup>	ton (N.O.)	I <sub>F</sub> = 10 mA, V <sub>O</sub> = 5 V, PW ≥ 10 ms		0.5	1.5	ms
		ton (N.C.)			0.04	0.2	
	Turn-off Time <sup>*1</sup>	toff (N.O.)			0.04	0.2	
		toff (N.C.)			0.5	1.5	
	Isolation Resistance	R <sub>I-O</sub>	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1 MHz		1.1		pF/ch

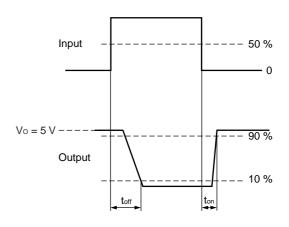
## \*1 Test Circuit for Switching Time



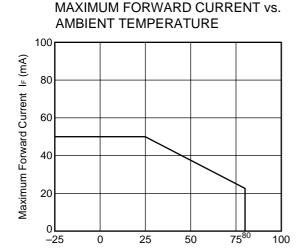
N.O. (between pin 5 and 6)



N.C. (between pin 7 and 8)

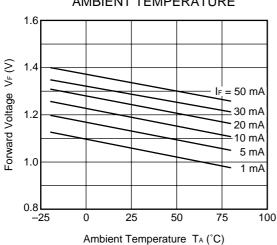


### **★** TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise specified)

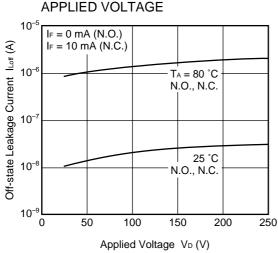


FORWARD VOLTAGE vs. AMBIENT TEMPERATURE

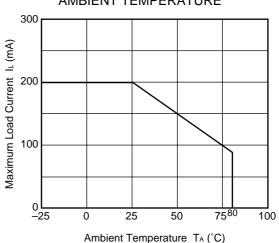
Ambient Temperature TA (°C)



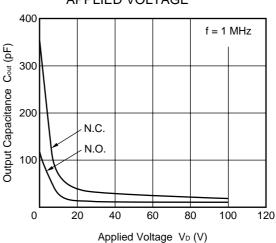
OFF-STATE LEAKAGE CURRENT vs.



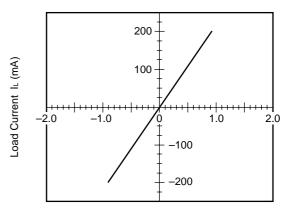
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



OUTPUT CAPACITANCE vs. APPLIED VOLTAGE

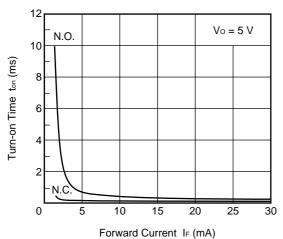


LOAD CURRENT vs. LOAD VOLTAGE

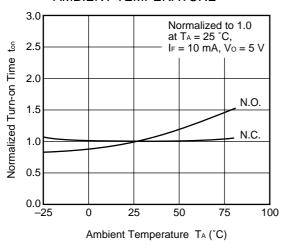


Load Voltage V<sub>L</sub> (V)

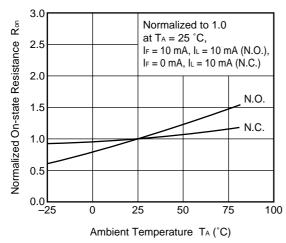
#### TURN-ON TIME vs. FORWARD CURRENT



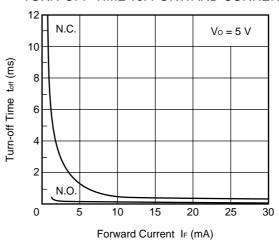
# NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE



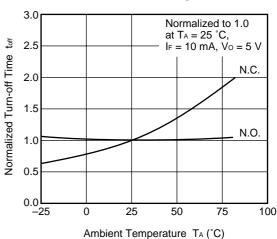
# NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



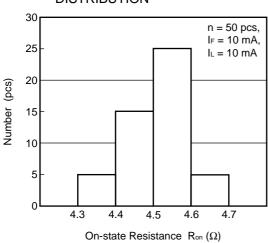
#### TURN-OFF TIME vs. FORWARD CURRENT



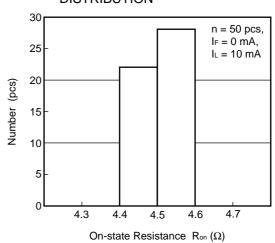
# NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



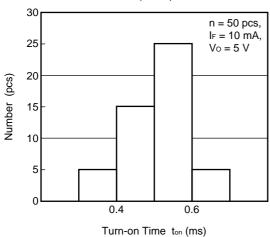
# ON-STATE RESISTANCE (N.O.) DISTRIBUTION



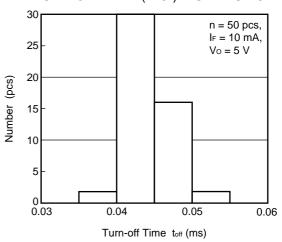
# ON-STATE RESISTANCE (N.C.) DISTRIBUTION



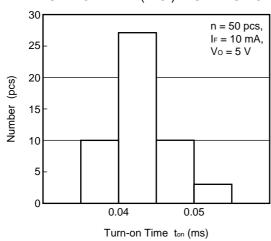
### TURN-ON TIME (N.O.) DISTRIBUTION



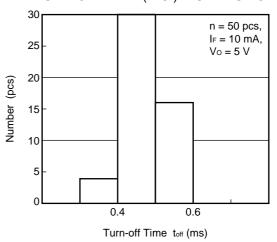
TURN-OFF TIME (N.O.) DISTRIBUTION



## TURN-ON TIME (N.C.) DISTRIBUTION

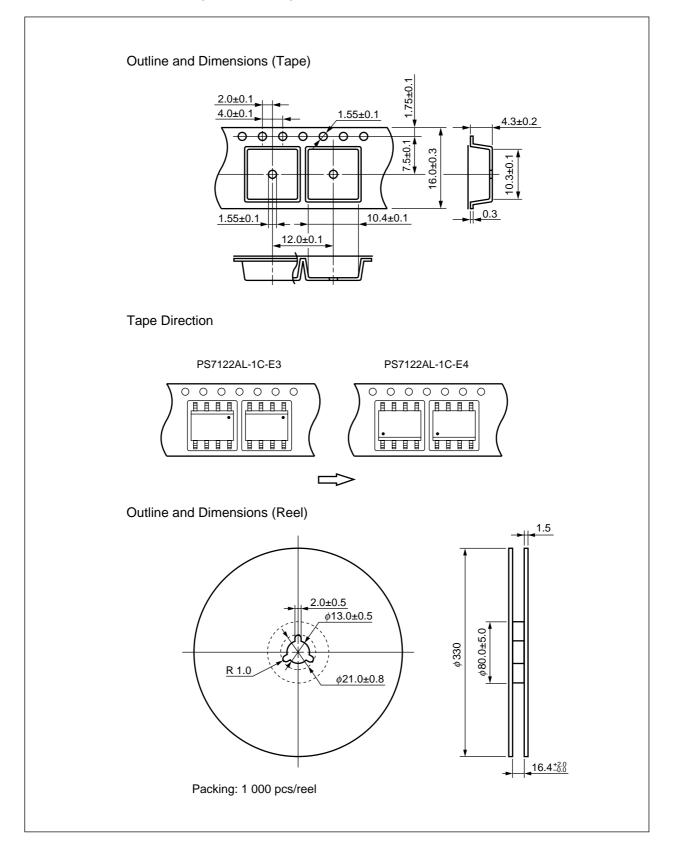


TURN-OFF TIME (N.C.) DISTRIBUTION



**Remark** The graphs indicate nominal characteristics.

### **★ TAPING SPECIFICATIONS (in millimeters)**



### RECOMMENDED SOLDERING CONDITIONS

### (1) Infrared reflow soldering

• Peak reflow temperature 235 °C (package surface temperature)

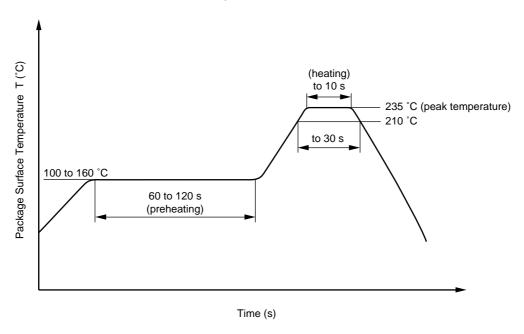
• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

### Recommended Temperature Profile of Infrared Reflow



# (2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

## (3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

#### **CAUTION**

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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